## NSN 5961-01-229-1461

**Fiig:** A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-229-1461 **Inclosure Material:** Glass **Overall Length:** 0.205 inches **Terminal Length:** 1.100 inches **Overall Diameter:** 0.107 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 repetitive peak reverse voltage, peak total value and 200.0 working peak reverse voltage, peak total value and 200.0 reverse voltage, instantaneous and 240.0 nonrepetitive peak reverse voltage, peak total value **Current Rating Per Characteristic:** 1.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No